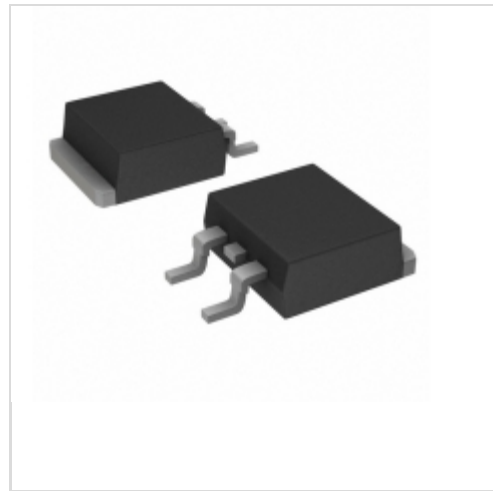


**UGB5JTBE3/45**

**Vishay / Semiconductor - Diodes Division**

DIODE GEN PURP 600V 5A TO263AB

Lead free / RoHS Compliant

Discrete Semiconductor Products

[UGB5JTBE3/45.pdf](#)

part#UGB5JTBE3/45 is available, see description of UGB5JTBE3/45 as below .  
 use the request quote form to request UGB5JTBE3/45 price and lead time.  
 Buy Electronic Components at zeanoit.com .we are an independent distributor of electronic components with extensive inventory in stock.  
 The price and lead time for UGB5JTBE3/45 depending on the quantity required, availability and warehouse location.Contact us today and our sales team will send you quotation soon.  
 Email: sales@zeanoit.com

**Out Stock**  
**0 pcs**  
 Minimum:1  
 Multiples:100  
 Manufacturer lead time 10 weeks

## Shopping Process

**1**
**Confirm the product**
**2**
**submit the order**
**3**
**payment**
**4**
**wait for delivery**
**5**
**receive the goods**

## Specifications

<b>Voltage - Forward (Vf) (Max) @ If:</b>	1.75V @ 5A
<b>Voltage - DC Reverse (Vr) (Max):</b>	600V
<b>Supplier Device Package:</b>	TO-263AB
<b>Speed:</b>	Fast Recovery = 200mA (Io)
<b>Series:</b>	-
<b>Reverse Recovery Time (trr):</b>	50ns
<b>Packaging:</b>	Tube
<b>Package / Case:</b>	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
<b>Operating Temperature - Junction:</b>	-55°C ~ 150°C
<b>Mounting Type:</b>	Surface Mount
<b>Diode Type:</b>	Standard
<b>Current - Reverse Leakage @ Vr:</b>	30µA @ 600V
<b>Current - Average Rectified (Io):</b>	5A
<b>Capacitance @ Vr, F:</b>	-

## Related products


**UGB8ATBE3/81**

 DIODE GEN PURP 50V 8A TO263AB  
[Vishay Semiconductor Diodes Division](#)

RFQ


**UGB6124AG**

 IC MOD DIODE 1PHASE BRIDGE UGB1  
[IXYS](#)

RFQ


**UGB8AT-E3/81**

 DIODE GEN PURP 50V 8A TO263AB  
[Vishay Semiconductor Diodes Division](#)

RFQ


**UGB5HTBE3/81**

 DIODE GEN PURP 500V 5A TO263AB  
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RFQ


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**UGB5JT-E3/81**

 DIODE GEN PURP 600V 5A TO263AB  
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RFQ


**UGB5JT**
[N/A](#)

RFQ

## Guess You May Looking For


**SIT1602BC-33-33N-35.840000T**

 -20 TO 70C, 5032, 50PPM, 3.3V, 3  
[SITIME](#)

RFQ


**SIT1602BI-23-18N-75.000000E**

 -40 TO 85C, 3225, 50PPM, 1.8V, 7  
[SITIME](#)

RFQ


**SIT1602AIB23-33E-50.000000E**

 OSC MEMS 50.0000MHZ H/LV-CMOS  
[SITIME](#)

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**SIT8008AI-73-33S-100.000000E**

 OSC MEMS 100.0000MHZ LVCMOS SMD  
[SITIME](#)

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**SIT1602BC-72-30E-10.000000E**

 -20 TO 70C, 2016, 25PPM, 3.0V, 1  
[SITIME](#)

RFQ


**SIT8008AI-13-33E-66.660000D**

 OSC MEMS 66.6600MHZ LVCMOS SMD  
[SITIME](#)

RFQ


**SIT1602BC-12-25S-33.330000E**

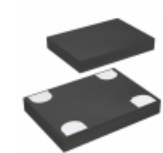
 -20 TO 70C, 2520, 25PPM, 2.5V, 3  
[SITIME](#)

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**SIT1602BC-82-33S-35.840000T**

 -20 TO 70C, 7050, 25PPM, 3.3V, 3  
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**SIT1602BC-81-18E-33.333330T**

 -20 TO 70C, 7050, 20PPM, 1.8V, 3  
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**SIT8918BE-12-33E-108.480000E**

 OSC MEMS 108.4800MHZ LVCMOS SMD  
[SITIME](#)

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